

MBRF1035 - MBRF10200

10.0 AMPS. Isolated Schottky Barrier Rectifiers

ITO-220AC

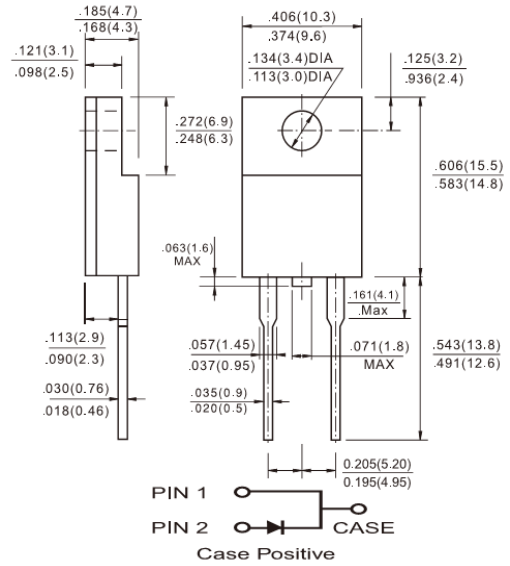


Features

- ✦ UL Recognized File # E-326243
- ✦ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✦ Metal silicon junction, majority carrier conduction
- ✦ Low power loss, high efficiency
- ✦ High current capability, low forward voltage drop
- ✦ High surge capability
- ✦ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✦ Guard-ring for overvoltage protection
- ✦ High temperature soldering guaranteed: 260°C/10 seconds, at terminals
- ✦ Green compound with suffix "G" on packing code & prefix "G" on datecode

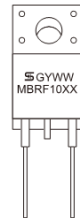
Mechanical Data

- ✦ Case: ITO-220AC molded plastic body
- ✦ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ✦ Polarity: As marked
- ✦ Mounting position: Any
- ✦ Mounting torque: 5 in. - lbs, max
- ✦ Weight: 1.74 grams



Dimensions in inches and (millimeters)

Marking Diagram



- MBRF10XX = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 1035	MBRF 1045	MBRF 1050	MBRF 1060	MBRF 1090	MBRF 10100	MBRF 10150	MBRF 10200	Unit	
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	200	V	
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	140	V	
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	200	V	
Maximum Average Forward Rectified Current	$I_{F(AV)}$	10								A	
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz) at $T_c=135^\circ C$	I_{FRM}	20								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150								A	
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1	0.5						A		
Maximum Instantaneous Forward Voltage (Note 2) $I_F=10A, T_A=25^\circ C$ $I_F=10A, T_A=125^\circ C$	V_F	0.70 0.57	0.80 0.70		0.85 0.71		1.05 -		V		
Maximum Reverse Current @ Rated VR $T_A=25^\circ C$ $T_A=125^\circ C$	I_R	0.1								mA	
		15	10	6	2						
Voltage Rate of Change (Rated V_R)	dV/dt	10000								V/us	
Typical Junction Capacitance	C_j	390	300		220				pF		
Typical Thermal Resistance	$R_{\theta JC}$	3								4	°C/W
Operating Temperature Range	T_J	- 65 to + 150								°C	
Storage Temperature Range	T_{STG}	- 65 to + 175								°C	

Note 1: 2.0uS Pulse Width, f=1.0KHz

Note 2: Pulse Test : 300uS Pulse Width, 1% Duty Cycle

RATINGS AND CHARACTERISTIC CURVES (MBRF1035 THRU MBRF10200)

FIG. 1 FORWARD CURRENT DERATING CURVE

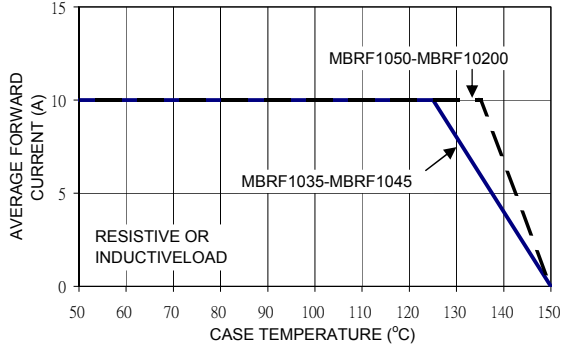


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

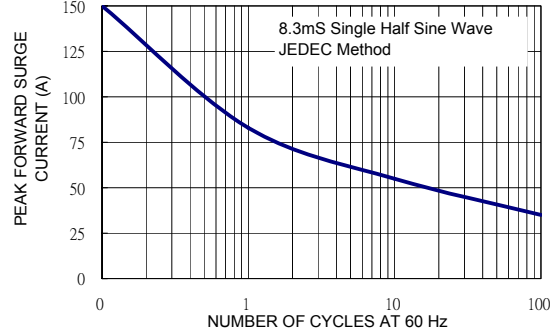


FIG. 3 TYPICAL FORWARD CHARACTERISTICS PER LEG

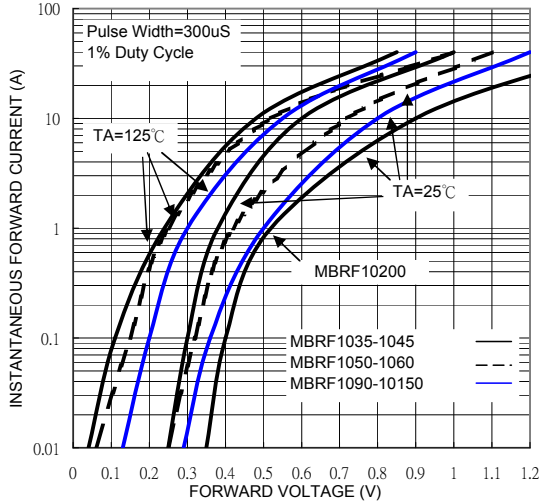


FIG. 4 TYPICAL REVERSE CHARACTERISTICS PER LEG

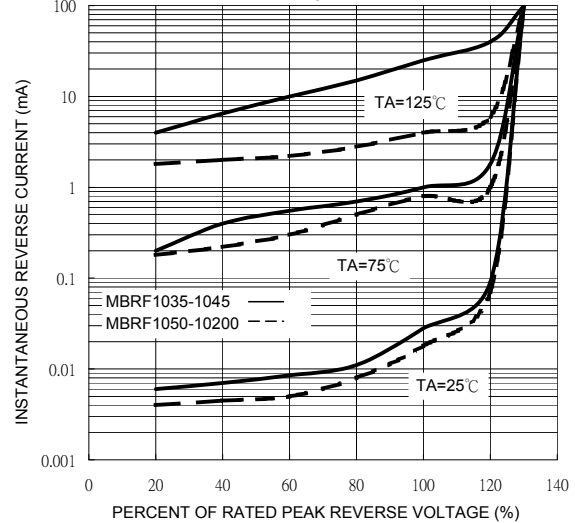


FIG. 5 TYPICAL JUNCTION CAPACITANCE PER LEG

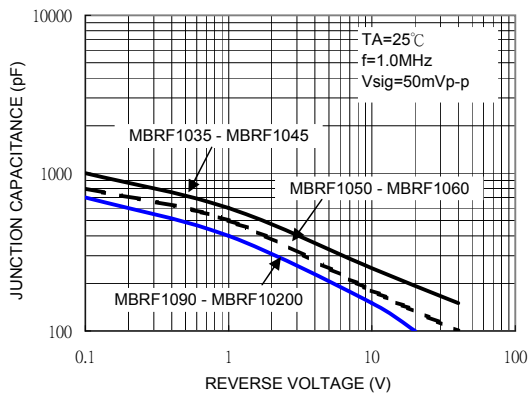


FIG. 6 TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG

